# NSN 5961-00-419-5360

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#### **Inclosure Material:**

Metal

### **Overall Length:**

Between 0.345 inches and 0.400 inches

## **Overall Diameter:**

Between 0.370 inches and 0.437 inches

## **Mounting Facility Quantity:**

1

#### **Internal Configuration:**

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

Between 0.424 inches and 0.437 inches

#### Thread Size:

0.190 inches

### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

5.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

2.0 watts small-signal input power, common-collector preset

#### **Special Features:**

Junction pattern arrangement: npn

# Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Thread Series Designator:

Unf

#### **Terminal Type And Quantity:**

3 tab, solder lug and 1 wire hook

#### **Specification Data:**

81349-mil-s-19500/374 government specification

#### Shelf Life:

N/a

# Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

